

MAXIM

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

General Description

The MAX338/MAX339 are monolithic, CMOS analog multiplexers (muxes). The 8-channel MAX338 is designed to connect one of eight inputs to a common output by control of a 3-bit binary address. The dual, 4-channel MAX339 is designed to connect one of four inputs to a common output by control of a 2-bit binary address. Both devices can be used as either a mux or a demux. On-resistance is 400Ω max, and the devices conduct current equally well in both directions.

These muxes feature extremely low off leakages (less than 20pA at $+25^\circ\text{C}$), and extremely low on-channel leakages (less than 50pA at $+25^\circ\text{C}$). The new design offers guaranteed low charge injection (1.5pC typ) and electrostatic discharge (ESD) protection greater than 2000V , per method 3015.7. These improved muxes are pin-compatible upgrades for the industry-standard DG508A and DG509A. For similar Maxim devices with lower leakage and charge injection but higher on-resistance, see the MAX328 and MAX329.

The MAX338/MAX339 operate from a single $+4.5\text{V}$ to $+30\text{V}$ supply or from dual supplies of $\pm 4.5\text{V}$ to $\pm 20\text{V}$. All control inputs (whether address or enable) are TTL compatible ($+0.8\text{V}$ to $+2.4\text{V}$) over the full specified temperature range and over the $\pm 4.5\text{V}$ to $\pm 18\text{V}$ supply range. These parts are fabricated with Maxim's 44V silicon-gate process.

Applications

Data-Acquisition Systems	Sample-and-Hold Circuits
Test Equipment	Heads-Up Displays
Military Radios	Communications Systems
Guidance and Control Systems	
PBX, PABX	

Features

- ◆ On-Resistance, $<400\Omega$ max
- ◆ Transition Time, $<500\text{ns}$
- ◆ On-Resistance Match, $<10\Omega$
- ◆ NO-Off Leakage Current, $<20\text{pA}$ at $+25^\circ\text{C}$
- ◆ 1.5pC Charge Injection
- ◆ Single-Supply Operation ($+4.5\text{V}$ to $+30\text{V}$) Bipolar-Supply Operation ($\pm 4.5\text{V}$ to $\pm 20\text{V}$)
- ◆ Plug-In Upgrade for Industry-Standard DG508A/DG509A
- ◆ Rail-to-Rail Signal Handling
- ◆ TTL/CMOS-Logic Compatible
- ◆ ESD Protection $>2000\text{V}$, per Method 3015.7

Ordering Information

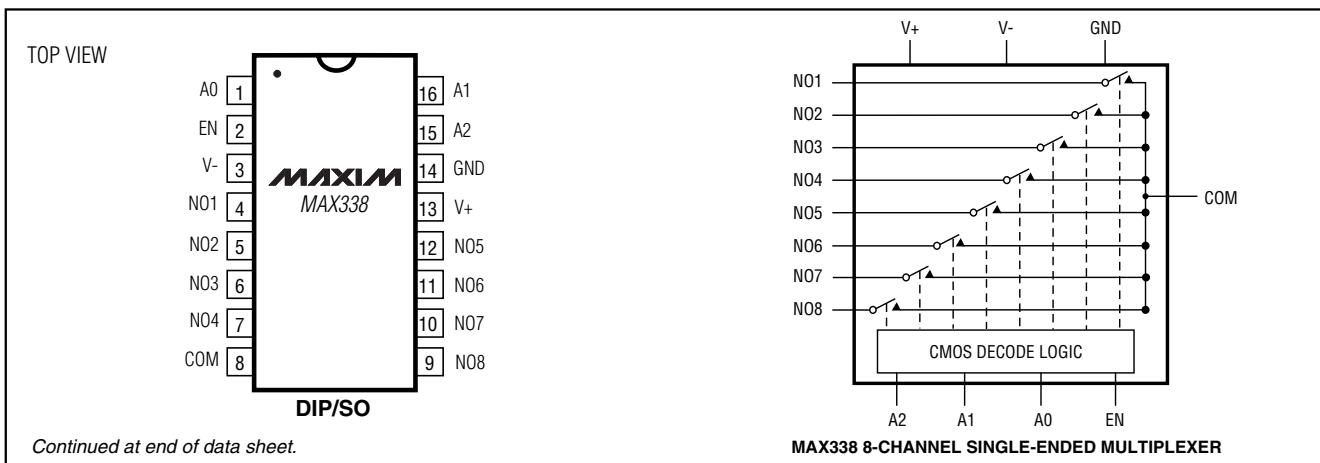
PART	TEMP. RANGE	PIN-PACKAGE
MAX338CPE	0°C to $+70^\circ\text{C}$	16 Plastic DIP
MAX338CSE	0°C to $+70^\circ\text{C}$	16 Narrow SO
MAX338C/D	0°C to $+70^\circ\text{C}$	Dice*
MAX338EGE	-40°C to $+85^\circ\text{C}$	16 QFN
MAX338EPE	-40°C to $+85^\circ\text{C}$	16 Plastic DIP
MAX338ESE	-40°C to $+85^\circ\text{C}$	16 Narrow SO
MAX338EJE	-40°C to $+85^\circ\text{C}$	16 CERDIP
MAX338MJE	-55°C to $+125^\circ\text{C}$	16 CERDIP**

Ordering Information continued at end of data sheet.

* Contact factory for dice specifications.

** Contact factory for availability.

Pin Configurations/Functional Diagrams/Truth Tables



Continued at end of data sheet.

MAX338/MAX339

MAXIM

Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to V-

V₊ -0.3V, 44V
GND -0.3V, 25V

Digital Inputs, NO, COM (Note 1) (V₋ - 2V) to (V₊ + 2V) or
30mA (whichever occurs first)

Continuous Current (any terminal) 30mA
Peak Current, NO or COM
(pulsed at 1ms, 10% duty cycle max) 100mA

Continuous Power Dissipation (TA = +70°C)

Plastic DIP (derate 10.53mW/°C above +70°C) 842mW
Narrow SO (derate 8.70mW/°C above +70°C) 696mW
QFN (derate 19.2mW/°C above +70°C) 1538mW
CERDIP (derate 10.00mW/°C above +70°C) 800mW

Operating Temperature Ranges

MAX33_C 0°C to +70°C
MAX33_E -40°C to +85°C
MAX33_MJE -55°C to +125°C

Storage Temperature Range -65°C to +150°C
Lead Temperature (soldering, 10sec) +300°C

Note 1: Signals on NO, COM, EN, A0, A1, or A2 exceeding V₊ or V₋ are clamped by internal diodes. Limit forward current to maximum current ratings.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V₊ = +15V, V₋ = -15V, GND = 0V, V_{AH} = +2.4V, V_{AL} = +0.8V, TA = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP	MAX	UNITS
SWITCH								
Analog Signal Range	V _{NO} , V _{COM}	(Note 3)			-15	15		V
On-Resistance	R _{ON}	I _{NO} = 0.2mA, V _{COM} = ±10V		TA = +25°C		220	400	Ω
		TA = T _{MIN} to T _{MAX}		500				
On-Resistance Matching Between Channels	ΔR _{ON}	I _{NO} = 0.2mA, V _{COM} = ±10V (Note 4)		TA = +25°C		4	10	Ω
		TA = T _{MIN} to T _{MAX}		15				
NO-Off Leakage Current (Note 5)	I _{NO(OFF)}	V _{COM} = +10V, V _{NO} = ±10V, V _{EN} = 0V		TA = +25°C		-0.02	0.001	0.02
				TA = T _{MIN} to T _{MAX}	C, E	-1.25	1.25	nA
					M	-20	20	
COM-Off Leakage Current (Note 5)	I _{COM(OFF)}	V _{NO} = ±10V, V _{COM} = +10V, V _{EN} = 0V	MAX338	TA = +25°C		-0.05	0.005	0.05
				TA = T _{MIN} to T _{MAX}	C, E	-3.25	3.25	nA
					M	-40	40	
		V _{NO} = +10V, V _{COM} = ±10V, V _{EN} = 0V	MAX339	TA = +25°C		-0.05	0.005	0.05
				TA = T _{MIN} to T _{MAX}	C, E	-1.65	1.65	nA
					M	-20	20	
COM-On Leakage Current (Note 5)	I _{COM(ON)}	V _{COM} = ±10V, V _{NO} = ±10V, sequence each switch on	MAX338	TA = +25°C		-0.05	0.006	0.05
				TA = T _{MIN} to T _{MAX}	C, E	-3.25	3.25	nA
					M	-40	40	
		V _{COM} = ±10V, V _{NO} = ±10V, sequence each switch on	MAX339	TA = +25°C		-0.05	0.008	0.05
				TA = T _{MIN} to T _{MAX}	C, E	-1.65	1.65	nA
					M	-20	20	

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

($V_+ = +15V$, $V_- = -15V$, $GND = 0V$, $V_{AH} = +2.4V$, $V_{AL} = +0.8V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN (Note 2)	TYP	MAX	UNITS
INPUT							
Input Current with Input Voltage High	I_{AH}	$V_A = 2.4V$ or $15V$		-1.0	0.001	1.0	μA
Input Current with Input Voltage Low	I_{AL}	$V_{EN} = 0V$ or $2.4V$, $V_A = 0V$		-1.0		1.0	μA
SUPPLY							
Power-Supply Range				± 4.5	± 20		V
Positive Supply Current	I_+	$V_{EN} = V_A = 0V$		$T_A = +25^\circ C$	50	100	μA
				$T_A = T_{MIN}$ to T_{MAX}		150	
Negative Supply Current	I_-	$V_{EN} = 2.4V$, $V_{A(ALL)} = 2.4V$		$T_A = +25^\circ C$	290	500	μA
				$T_A = T_{MIN}$ to T_{MAX}		600	
Negative Supply Current	I_-	$V_{EN} = 0V$ or $2.4V$, $V_{A(ALL)} = 0V$, $2.4V$ or $5V$		$T_A = +25^\circ C$	-1	1	μA
				$T_A = T_{MIN}$ to T_{MAX}	-10	10	
DYNAMIC							
Transistion Time	t_{TRANS}	Figure 2		$T_A = +25^\circ C$	200	500	ns
Break-Before-Make Interval	t_{OPEN}	Figure 4		$T_A = +25^\circ C$	10	140	ns
Enable Turn-On Time	$t_{ON(EN)}$	Figure 3		$T_A = +25^\circ C$	160	500	ns
				$T_A = T_{MIN}$ to T_{MAX}		750	
Enable Turn-Off Time	$t_{OFF(EN)}$	Figure 3		$T_A = +25^\circ C$	100	500	ns
				$T_A = T_{MIN}$ to T_{MAX}		750	
Charge Injection (Note 3)	Q	$C_L = 100pF$, $V_{NO} = 0V$, $R_S = 0\Omega$, Figure 6		$T_A = +25^\circ C$	1.5	5	pC
Off Isolation (Note 6)	V_{ISO}	$V_{EN} = 0V$, $R_L = 1k\Omega$, $f = 100kHz$		$T_A = +25^\circ C$		-75	dB
Crosstalk Between Channels	V_{CT}	$V_{EN} = 2.4V$, $f = 100kHz$, $V_{GEN} = 1V_{P-P}$, $R_L = 1k\Omega$, Figure 7		$T_A = +25^\circ C$		-92	dB
Logic Input Capacitance	C_{IN}	$f = 1MHz$		$T_A = +25^\circ C$		2	pF
NO-Off Capacitance	$C_{NO(OFF)}$	$f = 1MHz$, $V_{EN} = V_{NO} = 0V$, Figure 8		$T_A = +25^\circ C$		3	pF
COM-Off Capacitance	$C_{COM(OFF)}$	$f = 1MHz$, $V_{EN} = 0.8V$, $V_{COM} = 0V$, Figure 8	MAX338	$T_A = +25^\circ C$		11	pF
			MAX339			6	
COM-On Capacitance	$C_{COM(ON)}$	$f = 1MHz$, $V_{EN} = 2.4V$, $V_{COM} = 0V$, Figure 8	MAX338	$T_A = +25^\circ C$		16	pF
			MAX339			9	

MAX338/MAX339

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

ELECTRICAL CHARACTERISTICS—Single Supply

(V₊ = +12V, V₋ = 0V, GND = 0V, V_{AH} = +2.4V, V_{AL} = +0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	V _{NO} , V _{COM}	(Note 3)		0		12	V
On-Resistance	R _{ON}	I _{NO} = 0.2mA V _{COM} = 3V or 10V	T _A = +25°C	460		650	Ω
DYNAMIC							
Transition Time (Note 3)	t _{TRANS}	V _{NO1} = 8V, V _{NO8} = 0V, V _{IN} = 2.4V, Figure 1	T _A = +25°C	210		500	ns
Enable Turn-On Time (Note 3)	t _{ON(EN)}	V _{INH} = 2.4V, V _{INL} = 0V, V _{NO1} = 5V, Figure 3	T _A = +25°C	280		500	ns
Enable Turn-Off Time (Note 3)	t _{OFF(EN)}	V _{INH} = 2.4V, V _{INL} = 0V, V _{NO1} = 5V, Figure 3	T _A = +25°C	110		500	ns
Charge Injection (Note 3)	Q	C _L = 100pF, V _{NO} = 0V, R _S = 0Ω	T _A = +25°C	1.8		5	pC

Note 2: The algebraic convention where the most negative value is a minimum and the most positive value a maximum is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: ΔR_{ON} = R_{ON(MAX)} - R_{ON(MIN)}.

Note 5: Leakage parameters are 100% tested at the maximum rated hot temperature and guaranteed by correlation at +25°C.

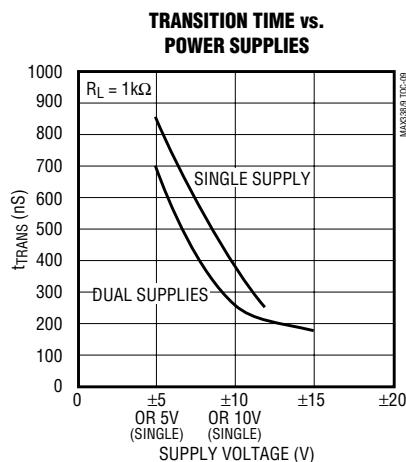
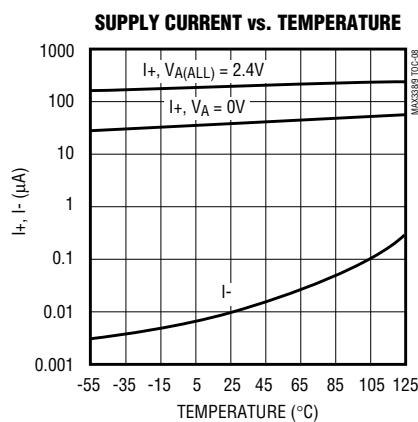
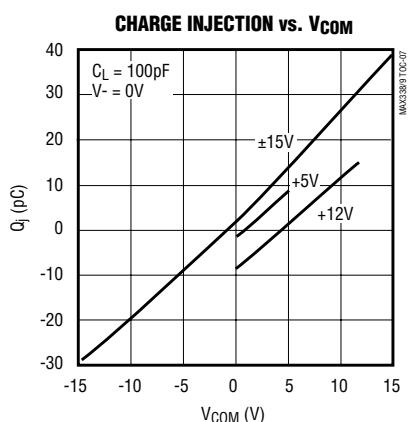
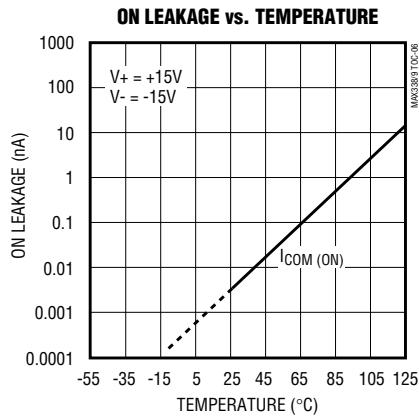
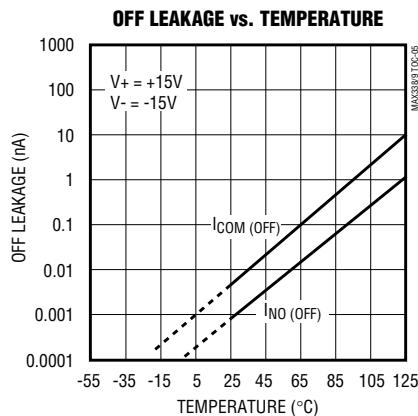
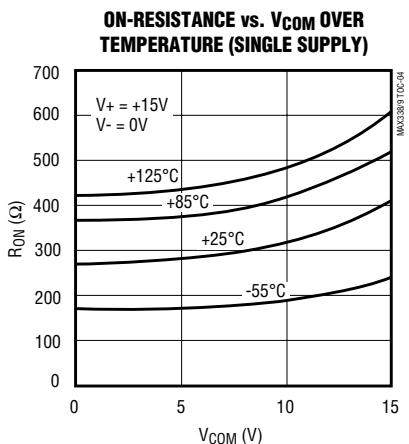
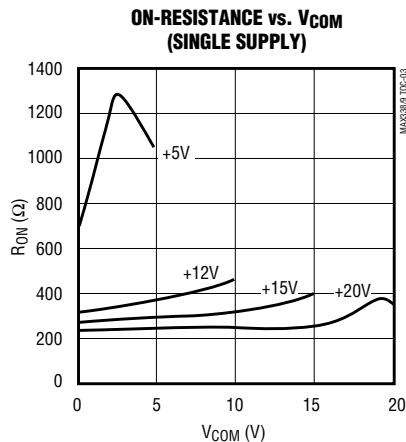
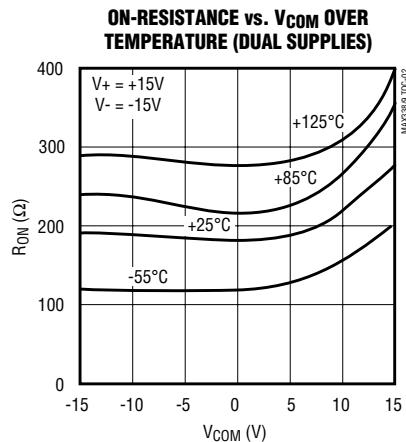
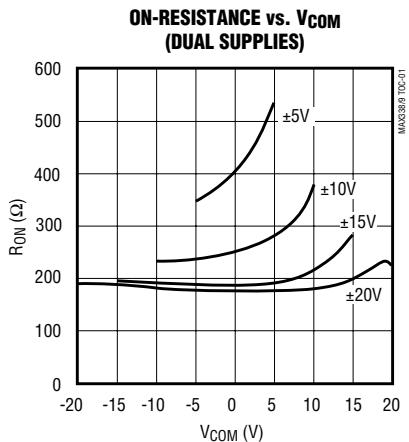
Note 6: Worst-case isolation is on channel 4 because of its proximity to the drain pin. Off isolation = 20log V_{COM}/V_{NO}, where V_{COM} = output and V_{NO} = input to off switch.

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

MAX338/MAX339



8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Pin Description

PIN				NAME	FUNCTION		
MAX338		MAX339					
DIP/SO	QFN	DIP/SO	QFN				
1, 15, 16,	15, 14, 13	—	—	A0, A2, A1	Address Inputs		
—	—	1, 16	15, 14	A0, A1	Address Inputs		
2	16	2	16	EN	Enable		
3	1	3	1	V-	Negative-Supply Voltage Input		
4–7	2–5	—	—	NO1–NO14	Analog Inputs—Bidirectional		
—	—	4–7	2–5	NO1A–NO4A	Analog Inputs—Bidirectional		
8	6	—	—	COM	Analog Output—Bidirectional		
—	—	8, 9	6, 7	COMA, COMB	Analog Outputs—Bidirectional		
9–12	7–10	—	—	NO8–NO5	Analog Inputs—Bidirectional		
—	—	10–3	8–11	NO4B–NO1B	Analog Inputs—Bidirectional		
13	11	14	12	V+	Positive-Supply Voltage Input		
14	12	15	13	GND	Ground		

Applications Information

Operation with Supply Voltages Other than 15V

Using supply voltages less than $\pm 15\text{V}$ will reduce the analog signal range. The MAX338/MAX339 switches operate with $\pm 4.5\text{V}$ to $\pm 20\text{V}$ bipolar supplies or with a $+4.5\text{V}$ to $+30\text{V}$ single supply. Connect V- to GND when operating with a single supply. Both device types can also operate with unbalanced supplies such as $+24\text{V}$ and -5V . The *Typical Operating Characteristics* graphs show typical on-resistance with 20V , 15V , 10V , and 5V supplies. (Switching times increase by a factor of two or more for operation at 5V .)

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings may cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs NO and COM. If power-supply sequencing is not possible, add two small signal diodes in series with supply pins for overvoltage protection (Figure 1). Adding diodes reduces the analog signal range to 1V below V+ and 1V above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 44V .

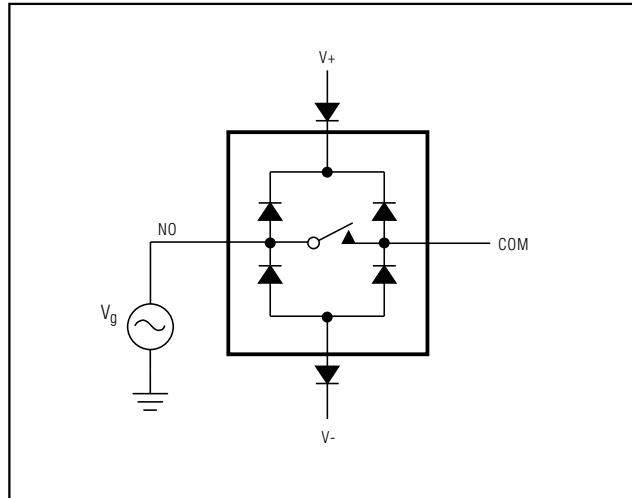


Figure 1. Overvoltage Protection Using External Blocking Diodes

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams

MAX338/MAX339

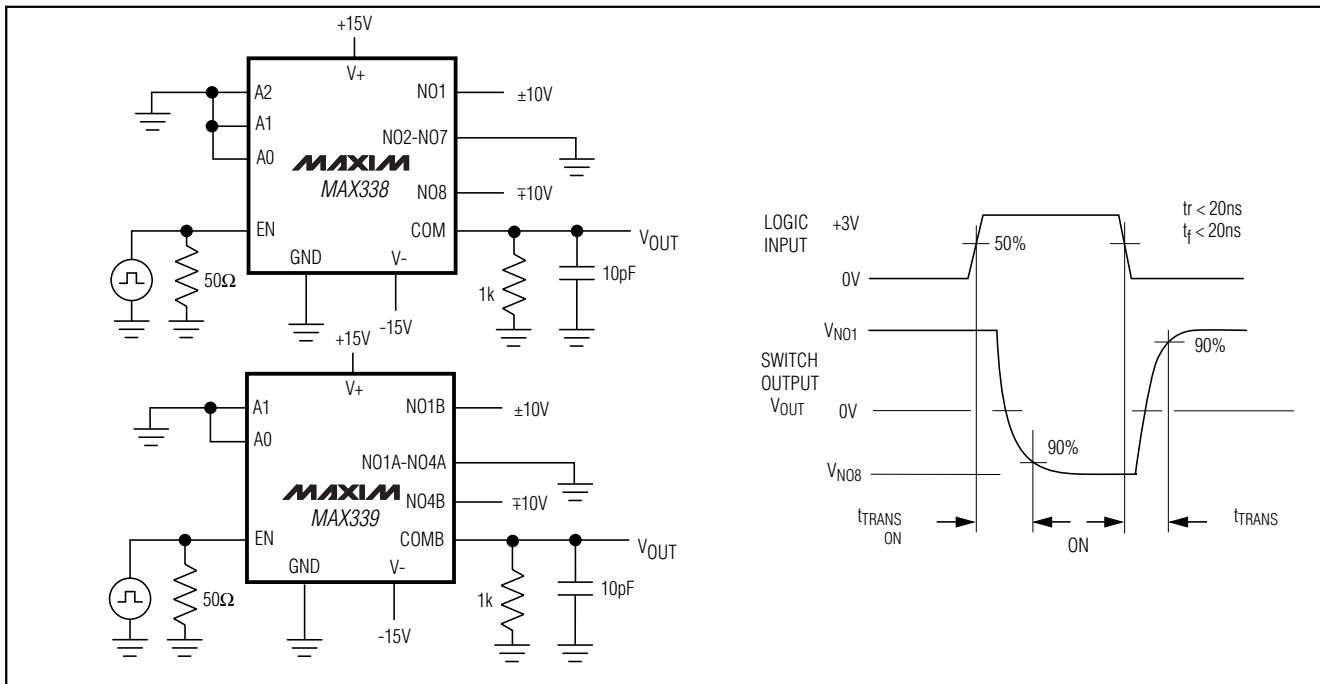


Figure 2. Transition Time

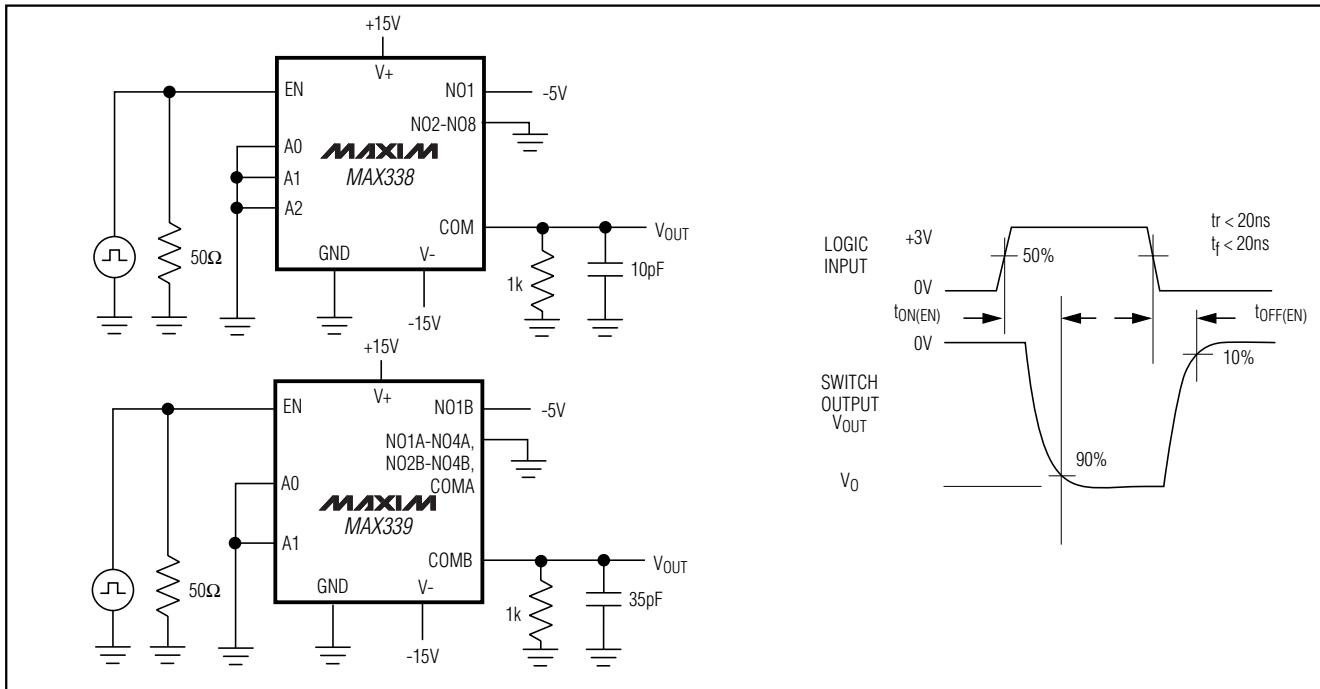


Figure 3. Enable Switching Time

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

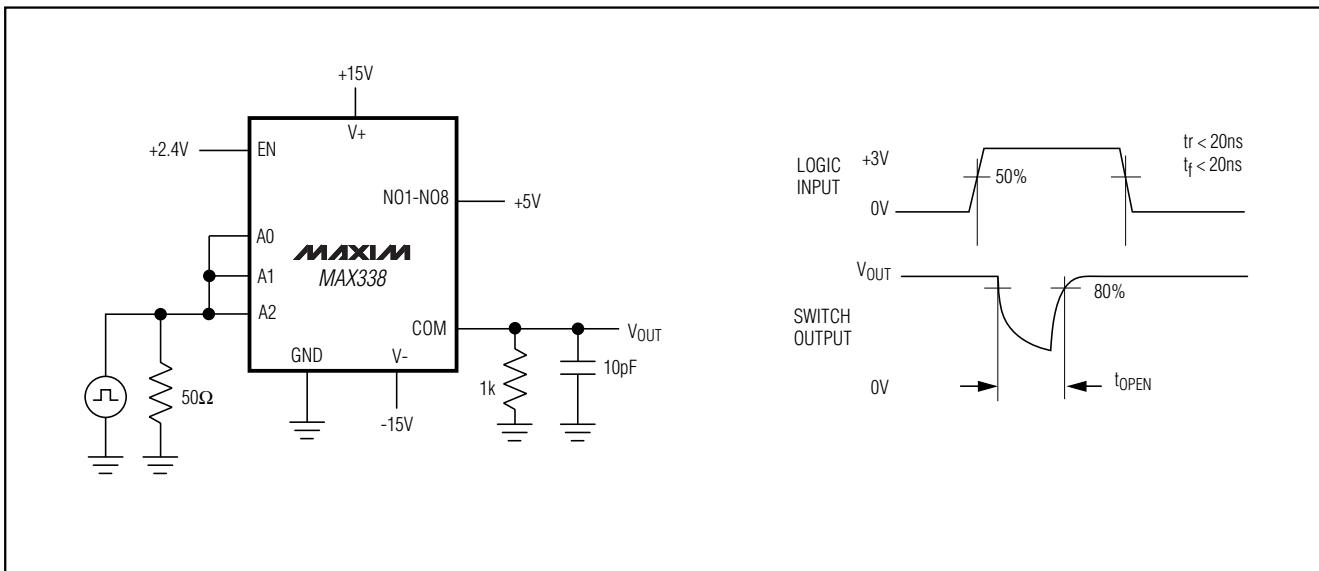


Figure 4. Break-Before-Make Interval

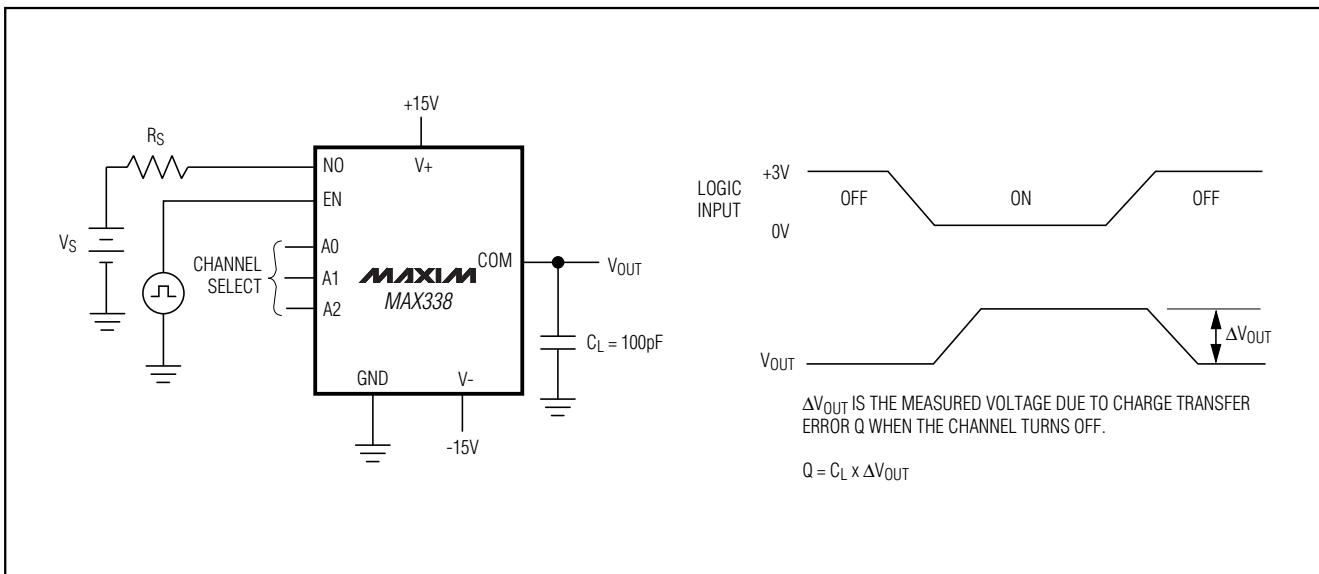


Figure 5. Charge Injection

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Test Circuits/Timing Diagrams (continued)

MAX338/MAX339

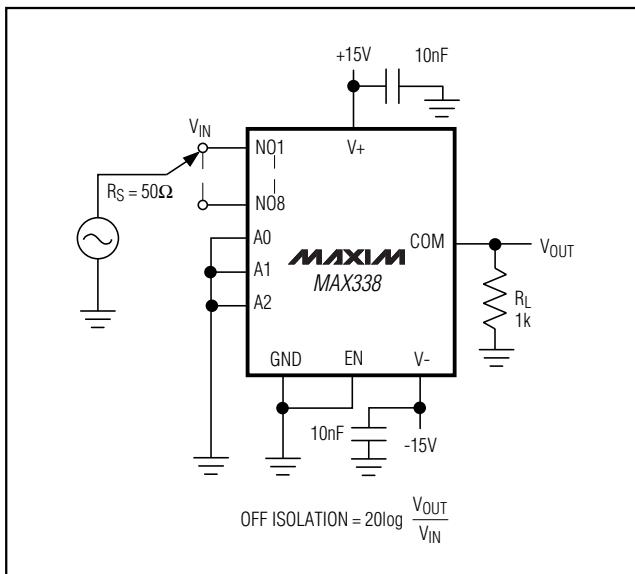


Figure 6. Off Isolation

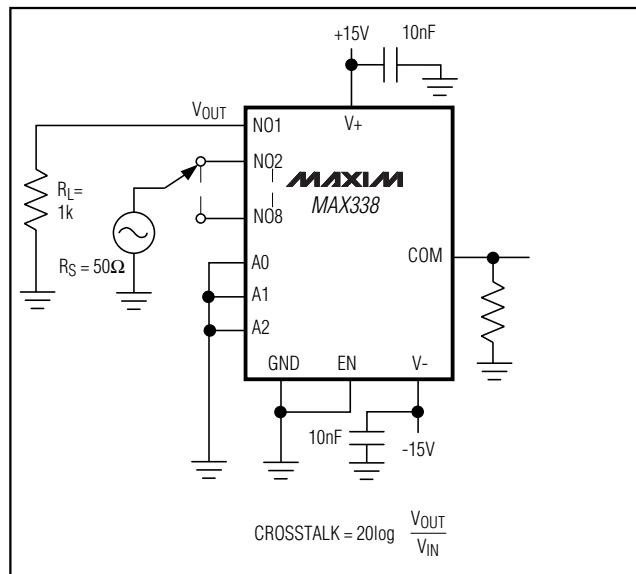


Figure 7. Crosstalk

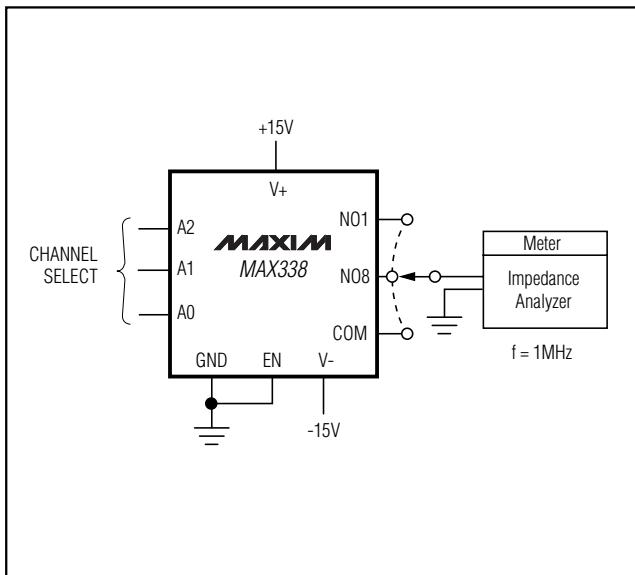
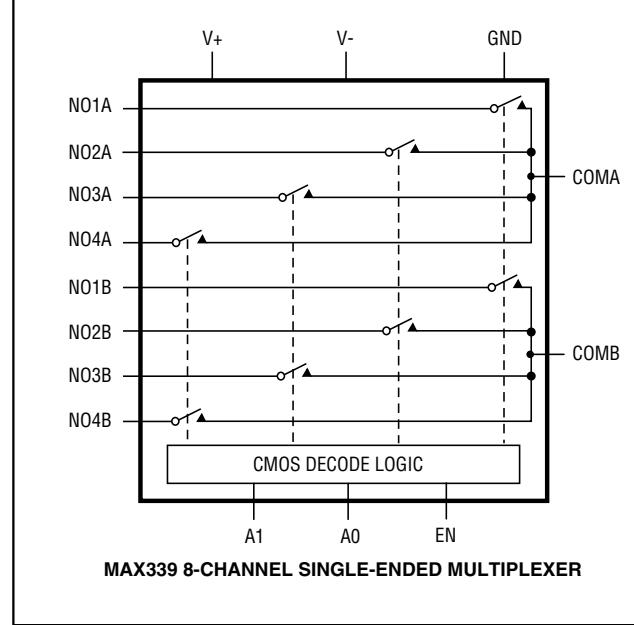
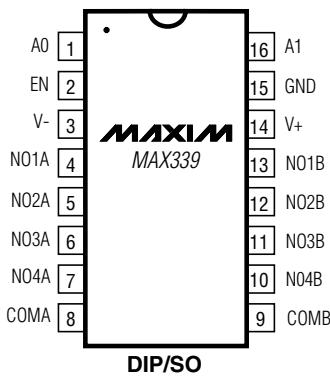


Figure 8. NO/COM Capacitance

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Pin Configurations/Functional Diagrams/Truth Tables (continued)

TOP VIEW



A2	A1	A0	EN	ON SWITCH
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

MAX338

LOGIC "0" $V_{AL} \leq 0.8V$, LOGIC "1" $V_{AH} \geq 2.4V$

A1	A0	EN	ON SWITCH
X	X	0	None
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

MAX339

LOGIC "0" $V_{AL} \leq 0.8V$, LOGIC "1" $V_{AH} \geq 2.4V$

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

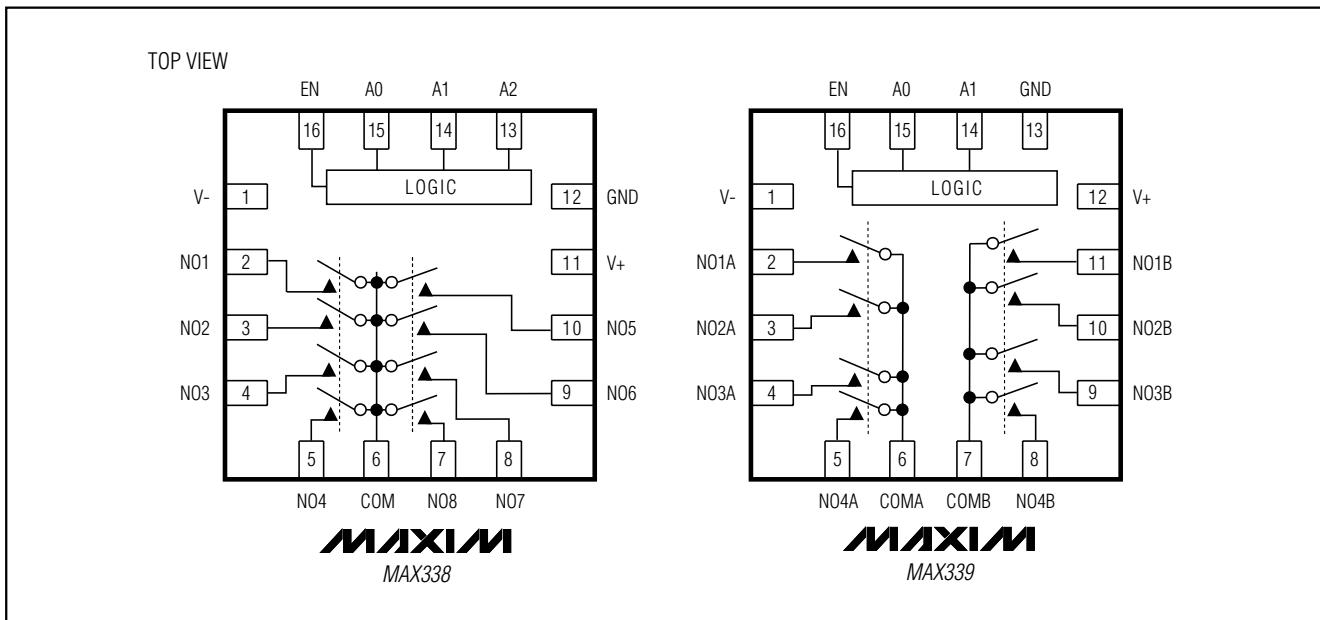
Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX339CPE	0°C to +70°C	16 Plastic DIP
MAX339CSE	0°C to +70°C	16 Narrow SO
MAX339C/D	0°C to +70°C	Dice*
MAX339EGE	-40°C to +85°C	16 QFN
MAX339EPE	-40°C to +85°C	16 Plastic DIP
MAX339ESE	-40°C to +85°C	16 Narrow SO
MAX339EJE	-40°C to +85°C	16 CERDIP
MAX339MJE	-55°C to +125°C	16 CERDIP**

* Contact factory for dice specifications.

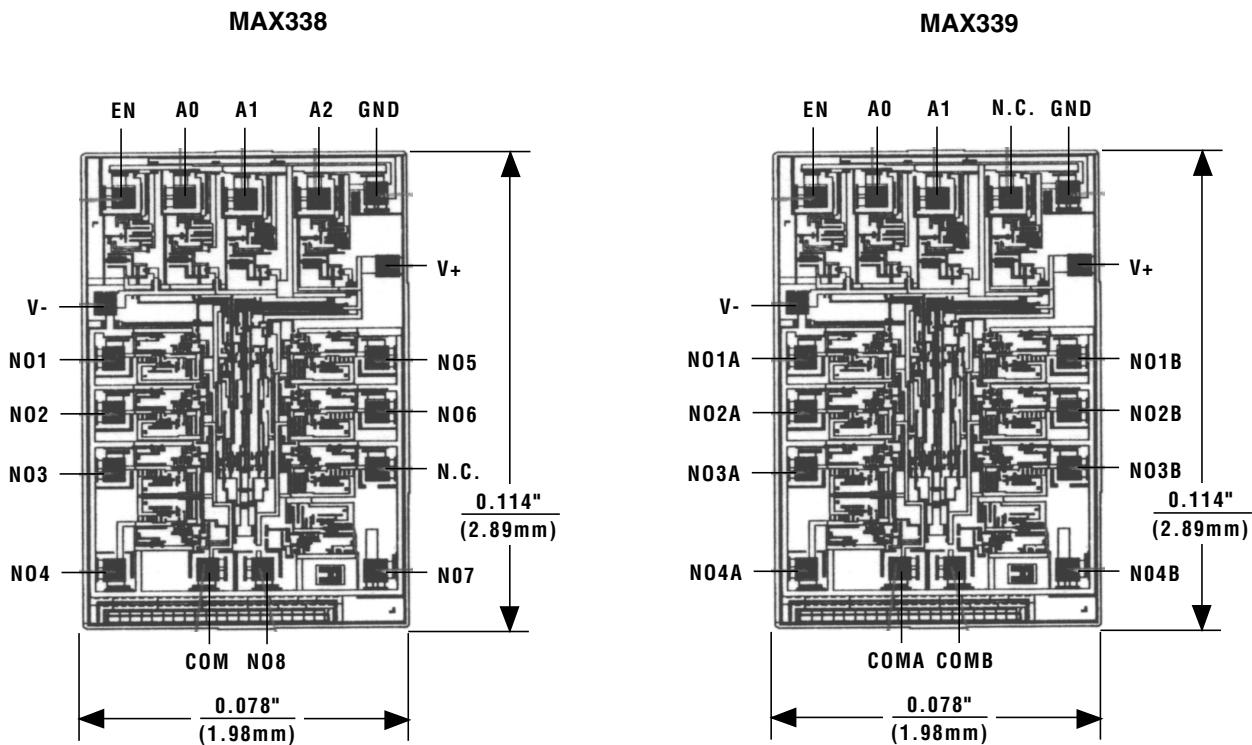
** Contact factory for availability.

Pin Configurations/Functional Diagrams/Truth Tables (continued)



8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Chip Topographies



N.C. = NO INTERNAL CONNECTION

TRANSISTOR COUNT: 224

SUBSTRATE IS INTERNALLY CONNECTED TO V+

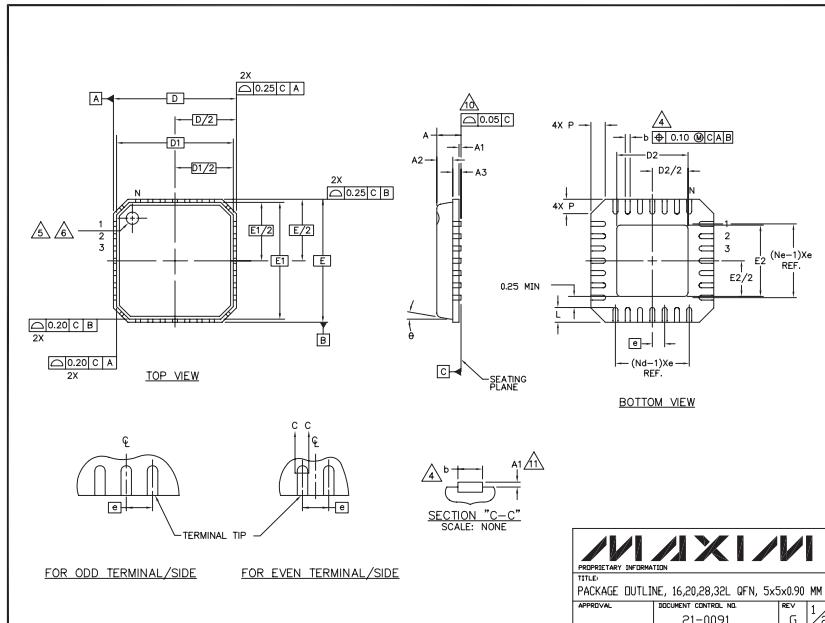
TRANSISTOR COUNT: 224

SUBSTRATE IS INTERNALLY CONNECTED TO V+

8-Channel/Dual 4-Channel, Low-Leakage, CMOS Analog Multiplexers

Package Information

MAX338/MAX339



NOTES:

1. DIE THICKNESS ALLOWABLE IS 0.305mm MAXIMUM (.012 INCHES MAXIMUM)
2. DIMENSIONING & TOLERANCES CONFORM TO ASME Y14.5M. - 1994.
3. N IS THE NUMBER OF TERMINALS.
 N_d IS THE NUMBER OF TERMINALS IN X-DIRECTION &
 N_e IS THE NUMBER OF TERMINALS IN Y-DIRECTION.
4. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED
BETWEEN 0.20 AND 0.25mm FROM TERMINAL TIP.
5. THE PIN #1 IDENTIFIER MUST BE EXISTED ON THE TOP SURFACE OF THE
PACKAGE BY USING INDENTATION MARK OR INK/ LASER MARKED.
6. EXACT SHAPE AND SIZE OF THIS FEATURE IS OPTIONAL.
7. ALL DIMENSIONS ARE IN MILLIMETERS.
8. PACKAGE WARPAGE MAX 0.05mm.
9. APPLIED FOR EXPOSED PAD AND TERMINALS.
EXCLUDE EMBEDDED PART OF EXPOSED PAD FROM MEASURING.
10. MEETS JEDEC MO220.
11. THIS PACKAGE OUTLINE APPLIES TO ANVIL SINGULATION (STEPPED SIDES)
AND TO SAW SINGULATION (STRAIGHT SIDES) QFN STYLES.

COMMON DIMENSIONS			
	MIN.	NOM.	MAX.
A	0.80	0.90	1.00
A1	0.00	0.01	0.05
A2	0.00	1.05	1.00
A3	0.20	REF.	
D	5.00	BSC	
D1	4.75	BSC	
E	5.00	BSC	
E1	4.75	BSC	
P	0°		12°
P	0		0.60
D2	1.25	—	3.25
E2	1.25	—	3.25

PITCH VARIATION B			PITCH VARIATION B			PITCH VARIATION C			PITCH VARIATION D		
(8)	MIN.	NOM.	MAX.	(8)	MIN.	NOM.	MAX.	(8)	MIN.	NOM.	MAX.
N	16	3	N	20	3	1	28	3	32	3	
N_d	4	3	N_d	5	3	N_d	7	3	N_d	8	
N_e	4	3	N_e	5	3	N_e	7	3	N_e	8	
L	0.35	0.55	0.75	L	0.35	0.55	0.75	L	0.35	0.40	0.50
b	0.28	0.33	0.40	b	0.23	0.28	0.35	b	0.18	0.23	0.30

PROPRIETARY INFORMATION		
TITLE: PACKAGE OUTLINE, 16,20,28,32L QFN, 5x5x0.90 MM		
APPROVAL	DOCUMENT CONTROL NO	REV
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Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

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